MSKSEMI















ESD

TVS

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PLED

Broduct data sheet





SOD-882

200 mW SOD-882 Surface Mount

This series of Zener diodes is packaged in a SOD- 882 surface mount package. They are designed to provide voltage regulation protection and are especially attractive in situations where space is at a premium. They are well suited for applications such as cellular phones, hand held portables, and high density PC boards.

Specification Features:

- Standard Zener Breakdown Voltage Range 2.4 V to 24 V
- Steady State Power Rating of 200 mW
- ESD Rating of Class 3 (>16 kV) per Human Body Model
- We declare that the material of product compliance with RoHS requirements and Halogen free.

Mechanical Characteristics:

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

LEAD FINISH: 100% Matte Sn (Tin)

MOUNTING POSITION: Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

MAXIMUM RATINGS

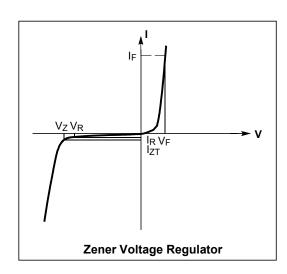
Rating	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, @ T _A = 25°C	P _D	200	mW
Junction and Storage Temperature Range	T _J , T _{stg}	-65 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted, V_F = 0.9 V Max. @ I_F = 10 mA for all types)

Symbol	Parameter				
Vz	Reverse Zener Voltage @ I _{ZT}				
I _{ZT}	Reverse Current				
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}				
I _{ZK}	Reverse Current				
Z _{ZK}	Maximum Zener Impedance @ Izĸ				
IR	Reverse Leakage Current @ V _R				
VR	Reverse Voltage				
lF	Forward Current				
VF	Forward Voltage @ I _F				
©V _Z	Maximum Temperature Coefficient of V _Z				
С	Max. Capacitance @V _R = 0 and f = 1 MHz				



Semiconductor

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted, $V_F = 0.9$ V Max. @ $I_F = 10$ mA for all types)

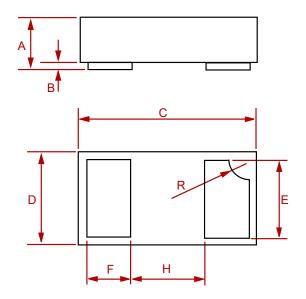
	Zener Voltage (Note		(Note	Zener Impedance		Leakage Current				С		
P/N	Device Marking	V _Z (V	olts)	@ I _{ZT}	Z _{ZT} @ I _{ZT}	Z _{ZK} (@ I _{ZK}	I _R @) V _R		Vz) @ Іzт	@ V _R = 0 f = 1 MHz
		Min	Max	mA	fi	fi	mA	μA	Volts	Min	Max	pF
LNZ8F2V4T5G-MS	J*	2.28	2.52	5	100	1000	1	50	1	-3.5	0	210
LNZ8F2V7T5G-MS	E*	2.57	2.84	5	100	1000	1	20	1	-3.5	0	210
LNZ8F3V0T5G-MS	T*	2.85	3.15	5	100	1000	1	10	1	-3.5	0	210
LNZ8F3V3T5G-MS	Q*	3.14	3.47	5	100	1000	1	10	1	-3.5	0	210
LNZ8F3V6T5G-MS	3*	3.42	3.78	5	100	1000	1	10	1	-3.5	0	210
LNZ8F3V9T5G-MS	V*	3.71	4.10	5	100	1000	1	5	1	-3.5	-2.5	210
LNZ8F4V3T5G-MS	Y*	4.09	4.52	5	100	1000	1	5	1	-3.5	0	210
LNZ8F4V7T5G-MS	7*	4.47	4.94	5	100	800	0.5	2	1	-3.5	0.2	150
LNZ8F5V1T5G-MS	4*	4.85	5.36	5	80	500	0.5	2	1.5	-2.7	1.2	130
LNZ8F5V6T5G-MS	5*	5.32	5.88	5	60	200	0.5	1	2.5	-2.0	2.5	115
LNZ8F6V2T5G-MS	6*	5.89	6.51	5	60	100	0.5	1	3	0.4	3.7	110
LNZ8F6V8T5G-MS	A*	6.46	7.14	5	40	60	0.5	0.5	3.5	1.2	4.5	105
LNZ8F7V5T5G-MS	D*	7.13	7.88	5	30	60	0.5	0.5	4	2.5	5.3	100
LNZ8F8V2T5G-MS	E*	7.79	8.61	5	30	60	0.5	0.5	5	3.2	6.2	90
LNZ8F9V1T5G-MS	F*	8.65	9.56	5	30	60	0.5	0.5	6	3.8	7	80
LNZ8F10VT5G-MS	J*	9.50	10.50	5	30	60	0.5	0.1	7	4.5	8	80
LNZ8F11VT5G-MS	K*	10.45	11.55	5	30	60	0.5	0.1	8	5.4	9	80
LNZ8F12VT5G-MS	L*	11.40	12.60	5	30	80	0.5	0.1	9	6	10	80
LNZ8F13VT5G-MS	P*	12.35	13.65	5	37	80	0.5	0.1	10	7	11	75
LNZ8F15VT5G-MS	Q*	14.25	15.75	5	42	80	0.5	0.1	11	9.2	13	70
LNZ8F16VT5G-MS	R*	15.20	16.80	5	50	80	0.5	0.1	12	10.4	14	65
LNZ8F18VT5G-MS	T*	17.10	18.90	5	50	80	0.5	0.1	14	12.4	16	60
LNZ8F20VT5G-MS	V*	19.00	21.00	5	55	100	0.5	0.1	15.4	14.4	18	55
LNZ8F22VT5G-MS	Y*	20.90	23.10	5	55	100	0.5	0.1	16.8	15.4	20	55
LNZ8F24VT5G-MS	S*	22.80	25.20	5	70	120	0.5	0.1	18.9	16.8	22	50

^{*}Rotated 90°.
**Rotated 270°.

^{1.} Zener voltage is measured with a pulse test current I_Z at an ambient temperature of 25°C.

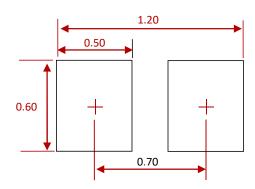


PACKAGE MECHANICAL DATA



Disa	Inc	hes	Millimeters			
Dim	MIN	MAX	MIN	MAX		
Α	0.0125	0.02	0.32	0.52		
В	0.000	0.002	0.00	0.05		
С	0.037	0.043	0.95	1.080		
D	0.022	0.027	0.55	0.680		
E	0.016	0.024	0.40	0.60		
F	0.008	0.012	0.20	0.30		
Н	0.015Typ.		0.40	Тур.		
R	0.001	0.005	0.05	0.15		

Suggested Pad Layout



NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.

REEL SPECIFICATION

P/N	PKG	QTY
LNZ8FXXXT5G-MS	S0D-882	10000



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